

KSC815

Low Frequency Amplifier & High Frequency Oscillator

- Collector-Base Voltage : V_{CBO}=60V
- Complement to KSA539
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	200	mA
P _C	Collector Power Dissipation	400	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =100μA, I _E =0	60			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	45			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E=10\mu A, I_C=0$	5			V
I _{CBO}	Collector Cut-off Current	V_{CB} =45V, I_E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB}=3V$, $I_{C}=0$			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =1V, I _C =50mA	40		400	
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =10V, I _C =10mA	0.6	0.65	0.9	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =150mA, I _B =15mA		0.15	0.4	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =150mA, I _B =15mA		0.83	1.1	V
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =10mA	100	200		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		4		pF

h_{FE} Classification

Classification	R	0	Y	G
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240	200 ~ 400

Typical Characteristics

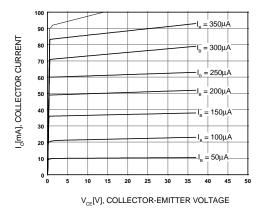


Figure 1. Static Characteristic

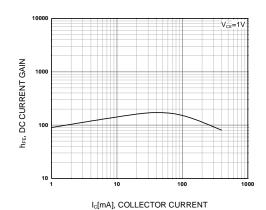


Figure 2. DC current Gain

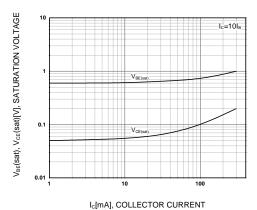


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

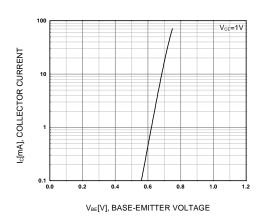


Figure 4. Base-Emitter On Voltage

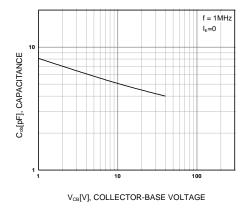


Figure 5. Collector Output Capacitance

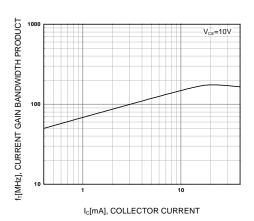
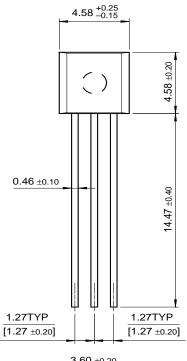


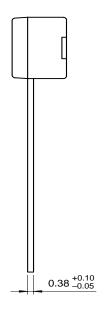
Figure 6. Current Gain Bandwidth Product

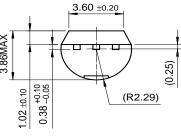
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Package Dimensions

TO-92







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